# Phase Control Thyristor Stud Types N0416S#020 to N0416S#080

The data sheet on the subsequent pages of this document is a scanned copy of existing data for this product.

(Rating Report 93NR1 Issue 1)

This data reflects the old part number for this product which is: N275PH02-08.

This part number must **NOT** be used for ordering purposes – please use the ordering particulars detailed below.

The limitations of this data are as follows: Only SC outline drawing (W18) in datasheet No reverse recovery information available

The following links will direct you to the appropriate outline drawings

Outline W18 – ¾" Ceramic stud

Outline W25 – ¾" Ceramic stud removed

Where any information on the product matrix page differs from that in the following data, the product matrix must be considered correct

An electronic data sheet for this product is presently in preparation.

For further information on this product, please contact your local ASM or distributor.

Alternatively, please contact Westcode as detailed below.

Ordering Particulars				
N0416	S#	<b>**</b>	0	
Fixed Type Code	SC – ¾" Ceramic stud SD – ¾" Ceramic stud removed	Voltage code V <sub>RRM</sub> /100 02-08	Fixed Code	
Typical Order C	code: N0416SC080, 3/4" Ceramic stud, 8	300V V <sub>RRM</sub> /V <sub>DRM</sub>		

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In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.

Rating Report: 93TR1

Date: 28th June, 1993

Origin: Q.E.L.

Pages: 12

## Thyristor Type N275PH02-08

Written by: M. Baker

Checked: BK

Approved:



### RATINGS

Voltage Grades : 02-08

 $v_{DSM}$ 

: 200-800V **V**RSM

: 300-900V V<sub>DRM</sub>, V<sub>RRM</sub> : 200-800V

 $I_{\mathrm{T(AV)}}$  : Single phase; 50 Hz, 180° sinewave

 $T_{CASE} = 94^{\circ}C$ : 226A

I<sub>T(rms)</sub> Max.

: 355A IT d.c. Max.

 $I_{TSM}$  : t = 10 ms half sinewave;  $T_{J(initial)}$  = 125°C;  $V_{RM} = 0.6 \ V_{RRM}(\text{MAX})$ : 355A : 6000A

 $I_{TSM}$  : t = 10 ms half sinewave;  $T_{J(initial)}$  = 125°C, : 6600A  $v_{RM} \leq 10v$ 

: t = 10 ms;  $T_{J(initial)} = 125^{\circ}\text{C}$ ;  $V_{RM} = 0.6V_{RRM}(MAX)$ :  $180 \times 10^3 \text{A}^2 \text{SECS}$  $I^2t$ 

: t = 10 ms;  $T_{J(initial)}$  = 125°C;  $V_{RM}$   $\leq$  10V : 218 x 10<sup>3</sup>A<sup>2</sup>SECS  $I^2t$ 

: t = 3 ms;  $T_{J(initial)}$  = 125°C;  $V_{RM}$   $\leq$  10V:  $165 \times 10^3 \text{A}^2 \text{SECS}$ 

di/dt : (Repetitive)  $T_J = 125$ °C; Gate: 20V, 20ohms

Rise time 1 $\mu$ s : 500A/µs

 $\mathbf{I}_{\mathrm{FGM}}$  : Anode positive with respect to cathode : 19A

 ${
m V}_{\rm FGM}$  : Anode positive with respect to cathode : 18V

V<sub>RGM</sub>:

5V  $P_{G}(AV)$ :

2W  $P_{GM}$ 

: 100W  $v_{
m GD}$ :

: 0.25V  $T_{\rm C}$  operating range

: -40°C to 125°C  ${f T}_{
m stg}$  Non operating

: -40°C to 150°C

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# CHARACTERISTICS (maximum values unless stated otherwise)

```
I_{GT}: T_J = 25°C
                                                                               : 150mA
     I_H : T_J = 25°C
                              V_A = 6V; I_A = 1A
                                                                               : 400mA
    V_{GT}: T_J = 25^{\circ}C
                                                                               : 3V
    V_O: T_J = 125°C
                                                                               : 0.85V
        T_{J} = 125^{\circ}C
                                                                              : 0.535m\Omega
             T_J = 25^{\circ}C
    В
         T_{\rm J} = 25^{\circ}{\rm C}
   C
         T_{J} = 25^{\circ}C
        : T_{J} = 25^{\circ}C
        : (Constant) T_J = 125^{\circ}C
   Α
        : (B x ln (i)) T_J = 125^{\circ}C
   В
       : (C x i) T_J = 125^{\circ}C
       : (D x \sqrt{i} ) T_J = 125°C
  v_{TM} : I_{TM} = 690A. T_J = 125°C
  R<sub>th(J-C)</sub>
                                                                             : 1.22V
                                                                            : 0.12 K/W
  Rth(C-HS)
                                                                            : 0.04 K/W
 dv/dt : Linear ramp to 0.8V_{DRM}(max); T_J = 125°C; Gate O/C
                                                  repetitive
                                                                           : 200V/µs*
 I_{DRM} : T_J = 125^{\circ}C ; V_{DM} = V_{DRM}(max)
                                                                            : 20mA
 I_{RRM} : T_J = 125^{\circ}C ; V_{RM} = V_{RRM}(max)
                                                                            : 20mA
 Q_{RA}
         : I_{TM} =
                          : dI/dt =
                                         A/\muS, 50% chord value
           V_{RM}^{IM} = 50V; T_J = 125^{\circ}C
t_q : I_{TM} =
                        :dI/dt =
                                          A/\mu S; T_J = 125^{\circ}C; V_{RM} = 50V
                         dv/dt = 200V/\mu s to 0.8 V_{DRM}
                         dv/dt = 20V/\mu s to 0.8 V_{DRM}
Mounting Torque
                                                                          : 2.50 - 2.77 Kgm
Outline Drawing
                                                                          : 101A225
Outline (JEDEC No.)
```

## Extension of Turn-off Time

This Report is applicable to other tq/reapplied dv/dt combinations when supply has been agreed by Sales/Production.

### \*Repetitive dv/dt

Higher dv/dt selections are available up to  $1000 \mathrm{V}/\mu\mathrm{S}$  on request.

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### Voltage Ratings

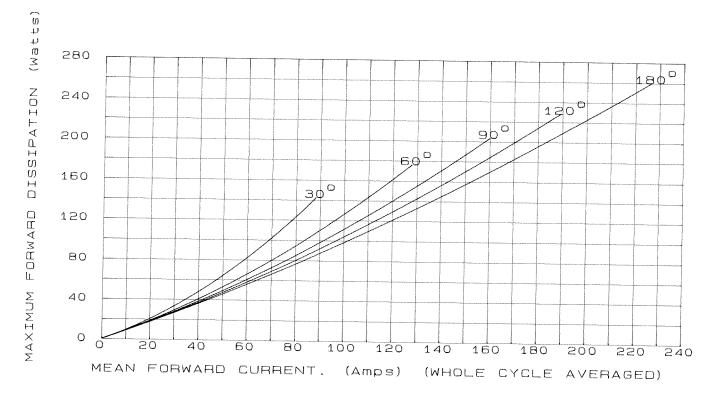
Voltage Grade 'H'	V <sub>DSM</sub> V <sub>DRM</sub> V <sub>RRM</sub>	V <sub>RSM</sub> V	$v_D v_R$
02	200	300	140
03	300	400	210
04	400	500	260
06	600	700	420
08	800	900	560

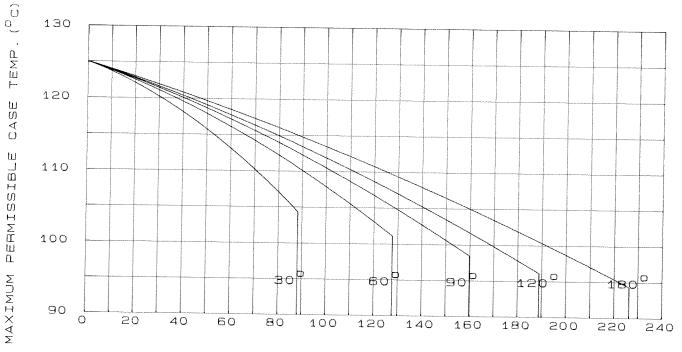
### Extension of Voltage Grades

This report is applicable to other and higher voltage grades when supply has been agreed by Sales/Production.

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### SINE WAVE



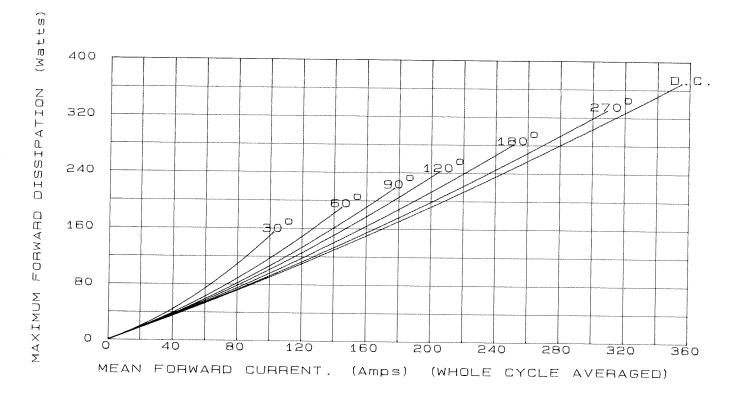


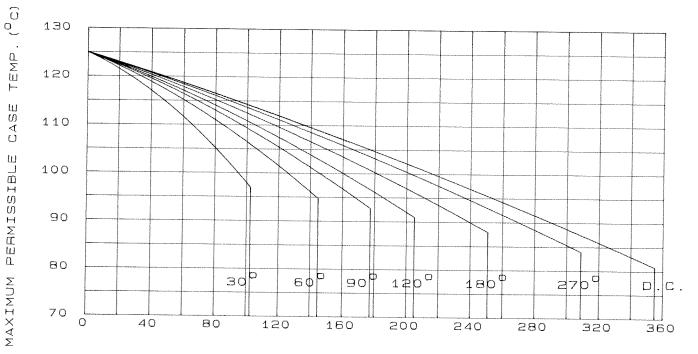
MAXIMUM PERMISSIBLE

MEAN FORWARD CURRENT. (Amps) (WHOLE CYCLE AVERAGED)

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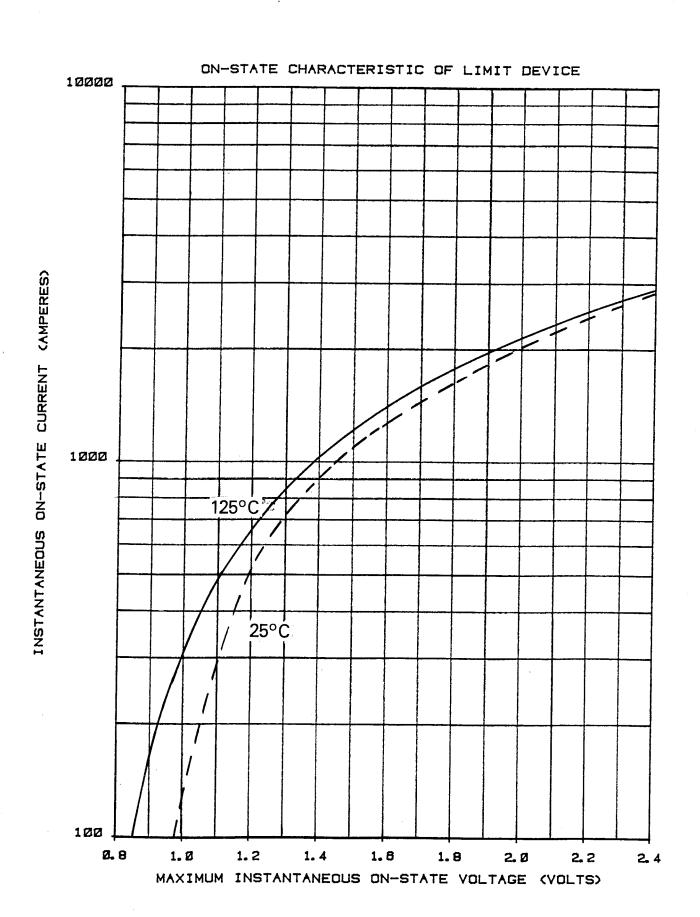
### SQUARE WAVE



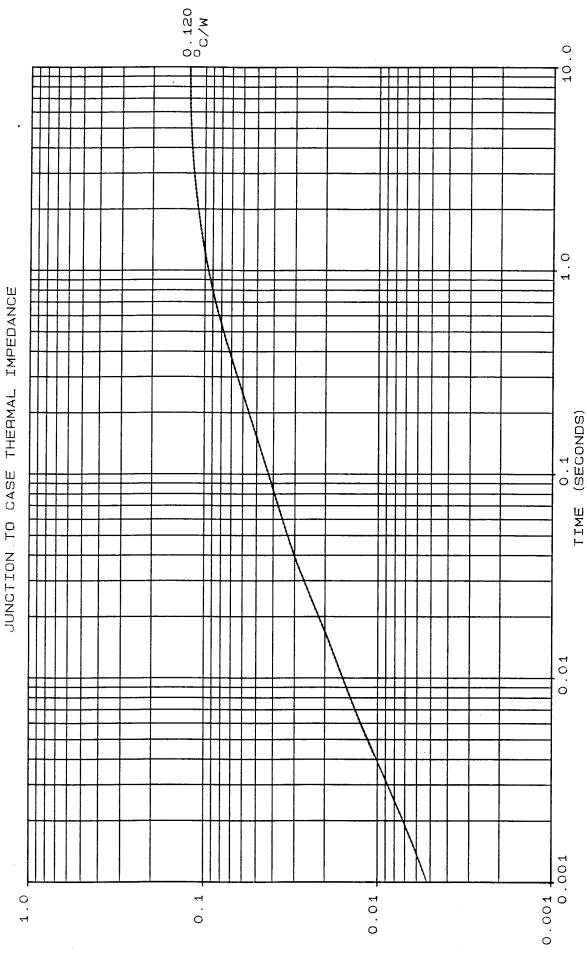


MEAN FORWARD CURRENT. (Amps) (WHOLE CYCLE AVERAGED)

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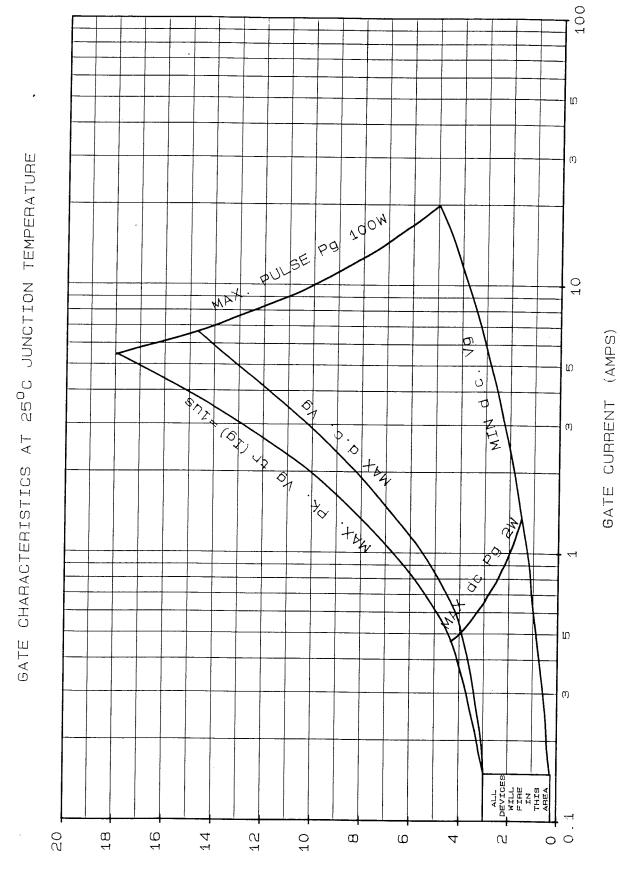


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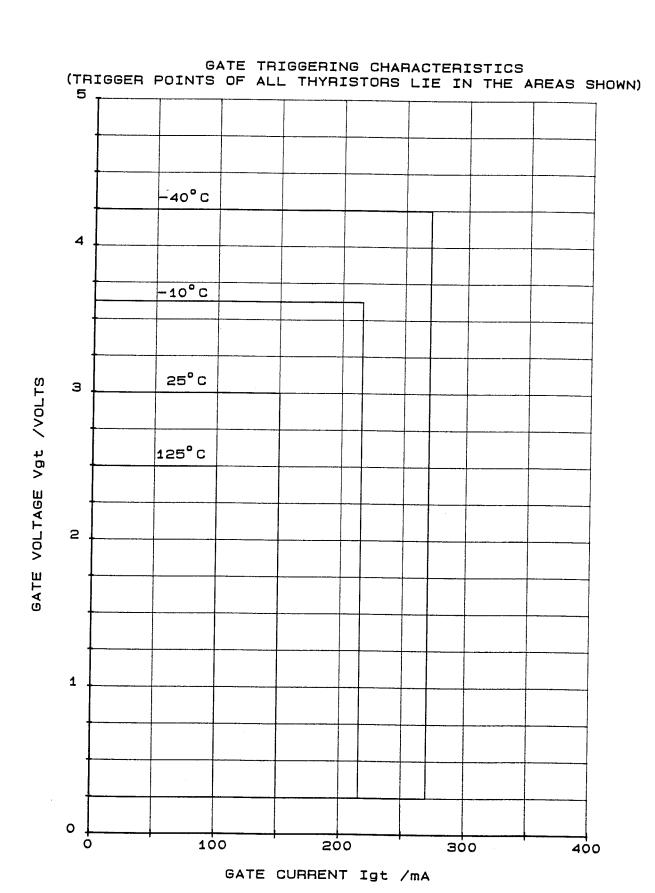
THERMAL IMPEDANCE (°C/WATT)

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GATE VOLTAGE (Vg) (VOLTS)

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Page No. 11 R.R. No. 93TR01 Page Iss. 1 R.R.Iss. 1 WYXIWNW IS (YWPS SECS) 104 (I-SM\* VRRM (I-SM\* 6ØXVR 100 50 DURATION OF SURGE (cycles at 50 Hz) 10 ហ 10 DURATION OF SURGE (mas) ហ ന

(Ifte BOXIVER)

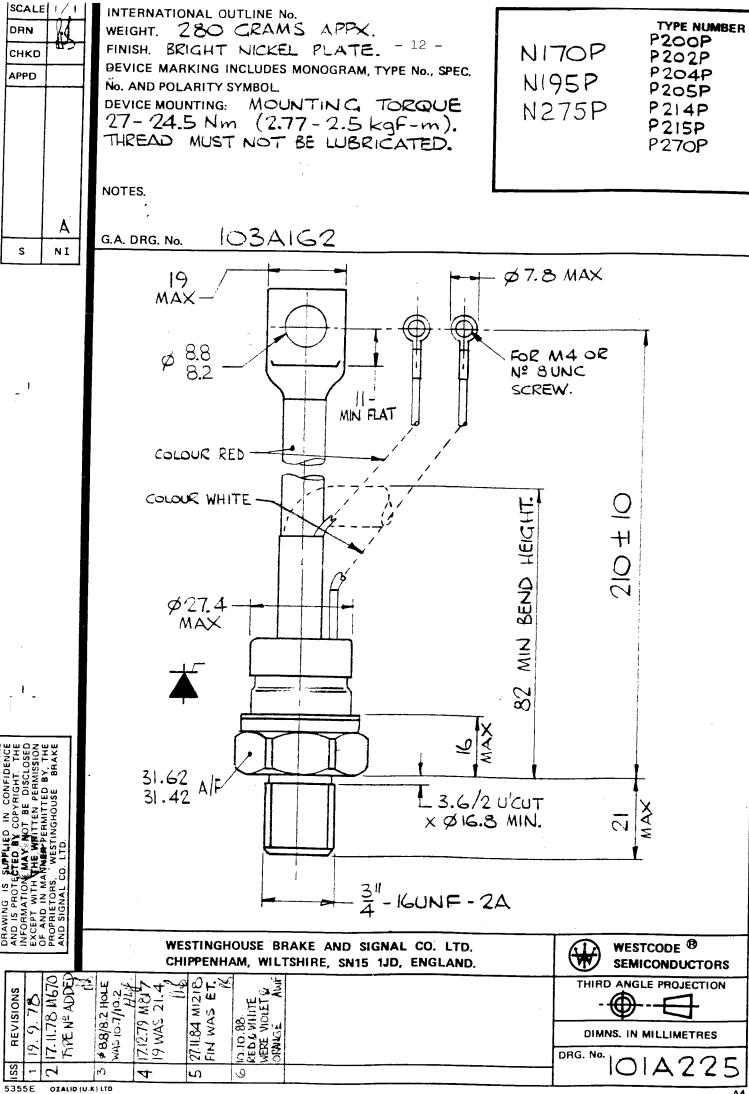
MAXIMUM NON REPETITIVE SURGE CURRENT AT INITIAL JUNCTION TEMPERATURE 125°C

GGATE MAY TEMPORARILY LOSE CONTROL OF CONDUCTION ANGLEJ

100

TOTAL PEAK HALF SINE SURGE CURRENT (KA)

10



A4